



SANYO Semiconductors

## DATA SHEET

# 2SC5227A — NPN Epitaxial Planar Silicon Transistor

## VHF to UHF Wide-Band Low-Noise Amplifier Applications

### Features

- Low-noise : NF=1.0dB typ (f=1GHz).
- High gain :  $|S_{21e}|^2=12\text{dB}$  typ (f=1GHz).
- High cut-off frequency :  $f_T=7\text{GHz}$  typ.

### Specifications

**Absolute Maximum Ratings** at  $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CB0}$		20	V
Collector-to-Emitter Voltage	$V_{CEO}$		10	V
Emitter-to-Base Voltage	$V_{EB0}$		2	V
Collector Current	$I_C$		70	mA
Collector Dissipation	$P_C$		200	mW
Junction Temperature	$T_J$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** at  $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=10\text{V}, I_E=0\text{A}$			1.0	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=1\text{V}, I_C=0\text{A}$			10	$\mu\text{A}$
DC Current Gain	$h_{FE}$	$V_{CE}=5\text{V}, I_C=20\text{mA}$	60*		270*	

Continued on next page.

\* : The 2SC5227A is classified by 20mA  $h_{FE}$  as follows :

Marking	LN3	LN4	LN5
Rank	3	4	5
$h_{FE}$	60 to 120	90 to 180	135 to 270

■ Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.

■ Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

**SANYO Semiconductor Co., Ltd.**

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

# 2SC5227A

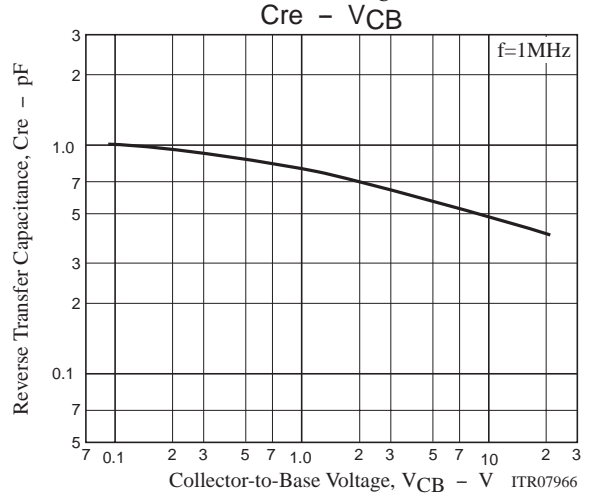
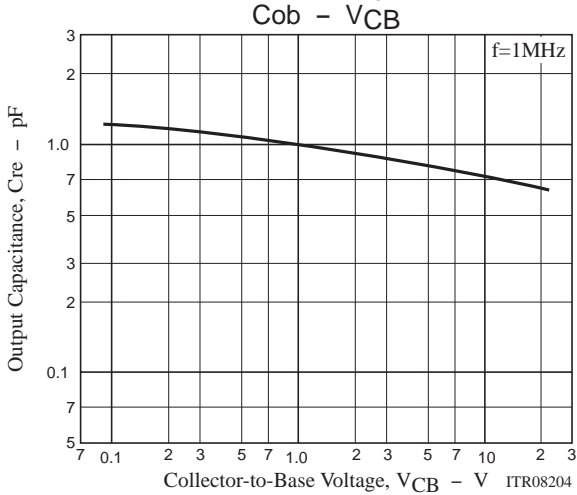
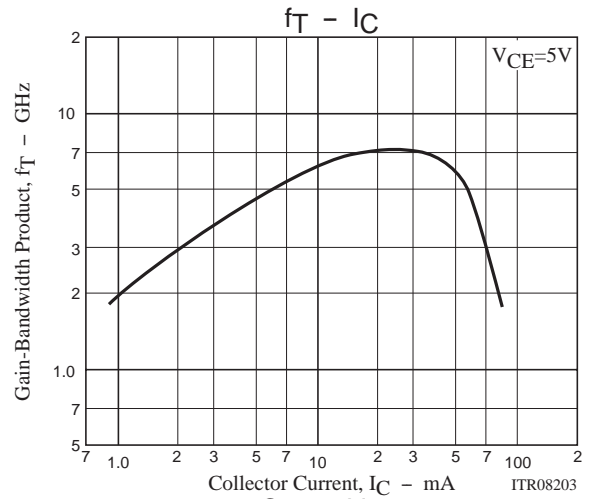
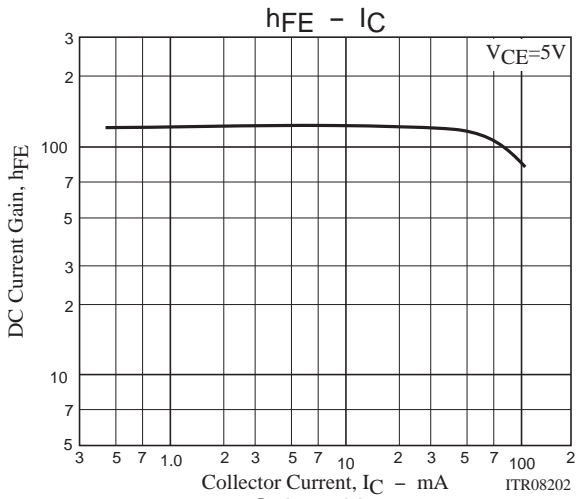
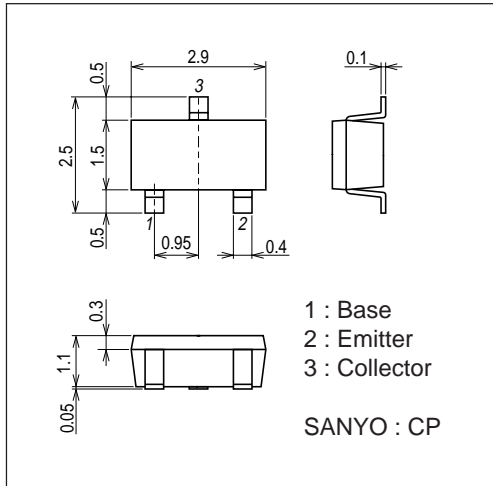
Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gain-Bandwidth Product	$f_T$	$V_{CE}=5V, I_C=20mA$	5	7		GHz
Output Capacitance	$C_{ob}$	$V_{CB}=10V, f=1MHz$		0.75	1.2	pF
Reverse Transfer Capacitance	$C_{re}$	$V_{CB}=10V, f=1MHz$		0.5		pF
Forward Transfer Gain	$ S_{21e} ^{21}$	$V_{CE}=5V, I_C=20mA, f=1GHz$	9	12		dB
	$ S_{21e} ^{22}$	$V_{CE}=2V, I_C=3mA, f=1GHz$		8		dB
Noise Figure	NF	$V_{CE}=5V, I_C=7mA, f=1GHz$		1.0	1.8	dB

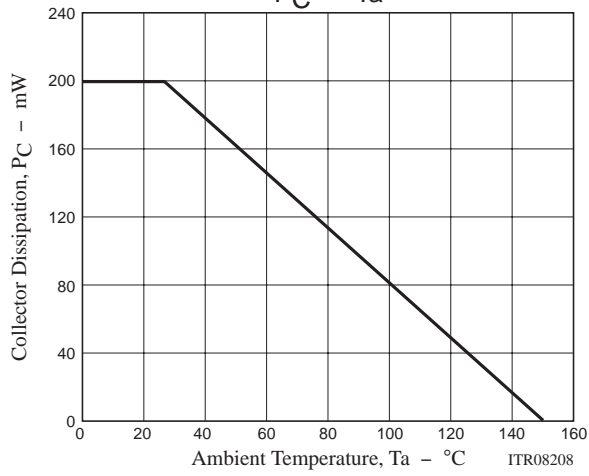
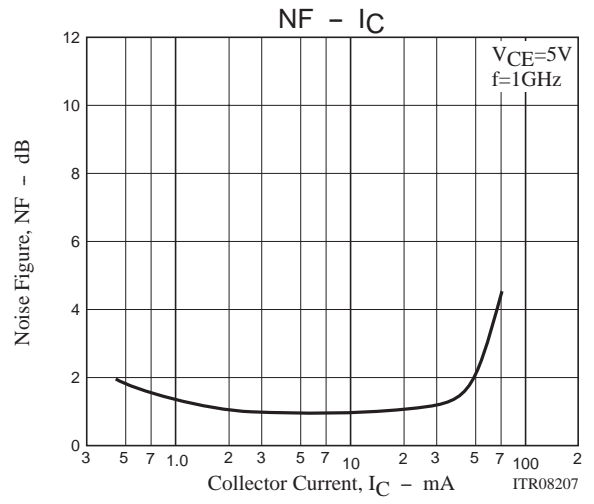
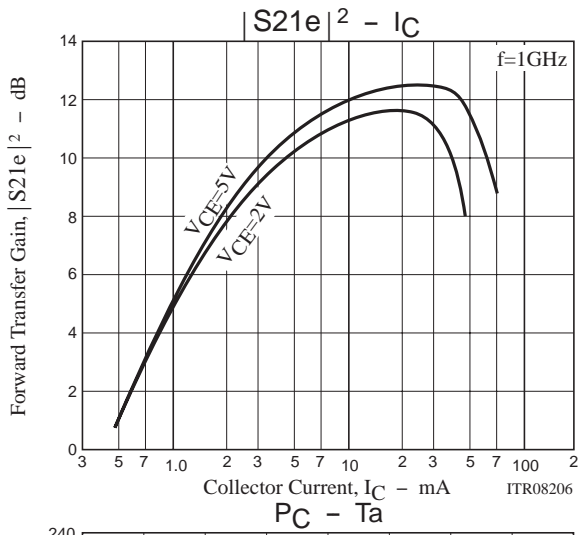
## Package Dimensions

unit : mm (typ)

7013A-009



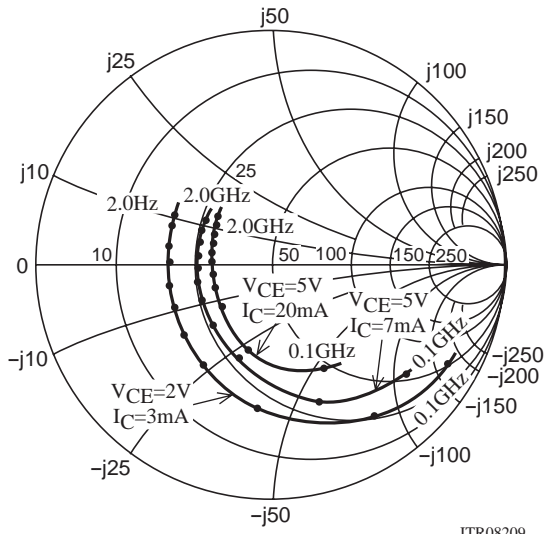
# 2SC5227A



# 2SC5227A

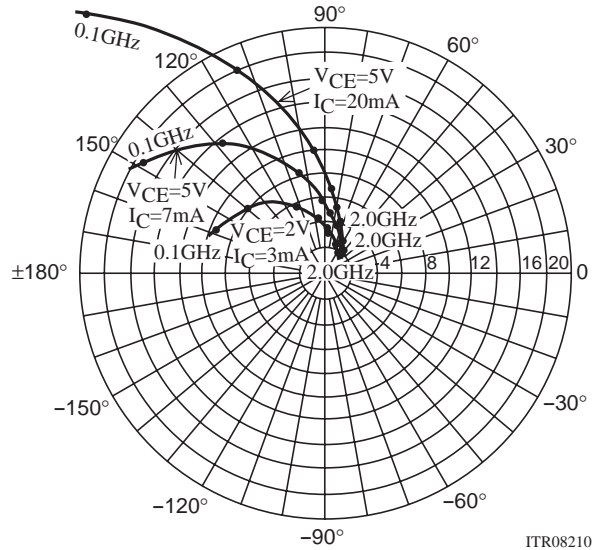
## S Parameters (Common emitter)

f=100MHz, 200MHz to 2000MHz(200MHz Step)



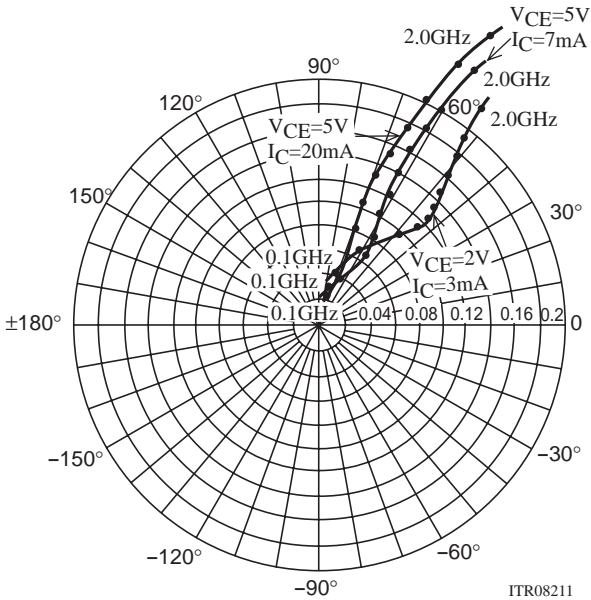
ITR08209

f=100MHz, 200MHz to 2000MHz(200MHz Step)



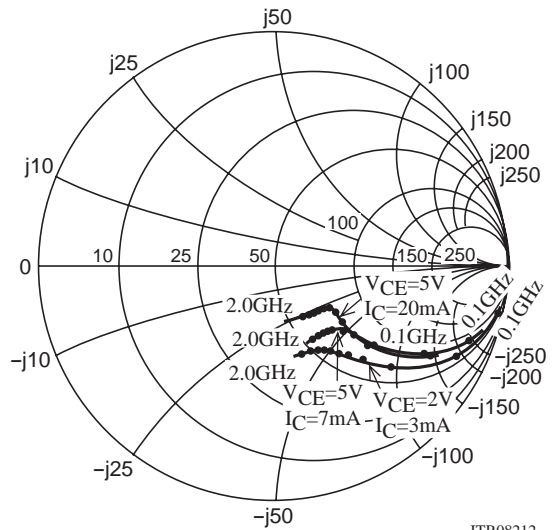
ITR08210

f=100MHz, 200MHz to 2000MHz(200MHz Step)



ITR08211

f=100MHz, 200MHz to 2000MHz(200MHz Step)



ITR08212

## 2SC5227A

### S Parameters (Common emitter)

$V_{CE}=5V, I_C=7mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
100	0.722	-41.6	17.352	148.7	0.029	70.9	0.883	-21.3
200	0.587	-73.2	13.419	127.6	0.046	60.8	0.710	-33.1
400	0.426	-113.0	8.371	105.1	0.067	56.9	0.507	-40.7
600	0.369	-136.6	5.914	92.7	0.084	58.4	0.423	-42.5
800	0.344	-152.9	4.593	83.9	0.102	60.3	0.382	-43.9
1000	0.334	-165.7	3.750	76.7	0.121	61.5	0.360	-46.3
1200	0.326	-177.9	3.178	70.3	0.141	62.0	0.350	-49.1
1400	0.324	172.3	2.784	64.9	0.162	61.8	0.341	-52.2
1600	0.328	163.4	2.476	59.5	0.183	61.2	0.334	-56.4
1800	0.335	154.5	2.246	54.6	0.204	60.5	0.328	-60.8
2000	0.346	147.5	3.073	50.0	0.226	59.6	0.328	-65.4

$V_{CE}=5V, I_C=20mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
100	0.477	-66.8	28.090	133.6	0.022	67.7	0.726	-32.7
200	0.358	-104.1	17.995	112.9	0.035	65.3	0.506	-41.6
400	0.288	-142.2	9.903	95.9	0.057	68.3	0.350	-42.4
600	0.273	-159.8	6.777	86.7	0.081	69.9	0.299	-41.8
800	0.270	-171.7	5.181	79.9	0.104	70.2	0.278	-43.2
1000	0.271	178.7	4.209	73.9	0.129	69.1	0.269	-45.9
1200	0.273	169.4	3.554	68.5	0.153	67.9	0.264	-49.6
1400	0.275	161.1	3.085	63.6	0.177	66.2	0.258	-53.3
1600	0.284	153.4	2.749	59.1	0.202	64.3	0.253	-58.3
1800	0.294	145.6	2.479	54.6	0.224	62.5	0.249	-63.4
2000	0.302	140.8	2.295	50.6	0.248	60.4	0.248	-68.7

$V_{CE}=2V, I_C=3mA, Z_O=50\Omega$

Freq(MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
100	0.858	-30.5	9.283	157.3	0.039	73.6	0.944	-15.6
200	0.769	-57.4	8.036	138.7	0.068	61.4	0.834	-27.5
400	0.607	-97.1	5.756	113.9	0.099	48.4	0.641	-40.5
600	0.528	-123.2	4.302	98.1	0.114	44.4	0.525	-46.5
800	0.486	-141.6	3.414	87.0	0.125	43.9	0.465	-50.2
1000	0.460	-156.4	2.834	78.0	0.137	45.4	0.429	-53.7
1200	0.453	-169.4	2.429	70.3	0.149	47.5	0.408	-57.3
1400	0.440	179.8	2.143	63.6	0.163	49.2	0.395	-60.9
1600	0.441	170.1	1.919	57.4	0.179	50.8	0.385	-65.4
1800	0.447	160.4	1.739	51.7	0.196	52.3	0.381	-70.1
2000	0.454	152.5	1.621	46.4	0.215	53.3	0.379	-75.2

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of May, 2008. Specifications and information herein are subject to change without notice.